



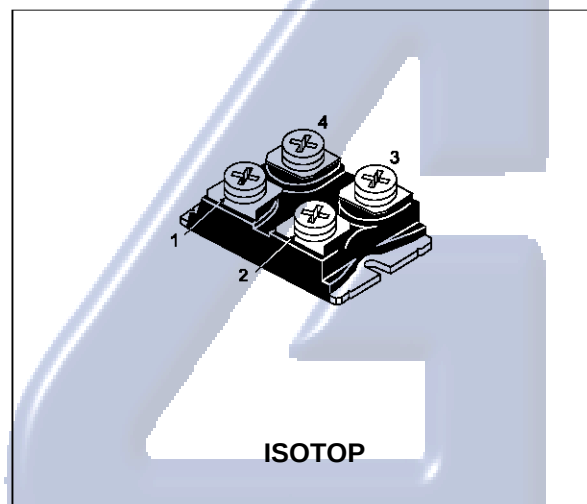
ESM4045DV

NPN DARLINGTON POWER MODULE

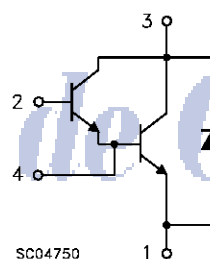
- HIGH CURRENT POWER BIPOLAR MODULE
- VERY LOW R_{th} JUNCTION CASE
- SPECIFIED ACCIDENTAL OVERLOAD AREAS
- ULTRAFAST FREEWHEELING DIODE
- ISOLATED CASE (2500V RMS)
- EASY TO MOUNT
- LOW INTERNAL PARASITIC INDUCTANCE

APPLICATIONS:

- MOTOR CONTROL
- SMPS & UPS
- DC/DC & DC/AC CONVERTERS
- WELDING EQUIPMENT



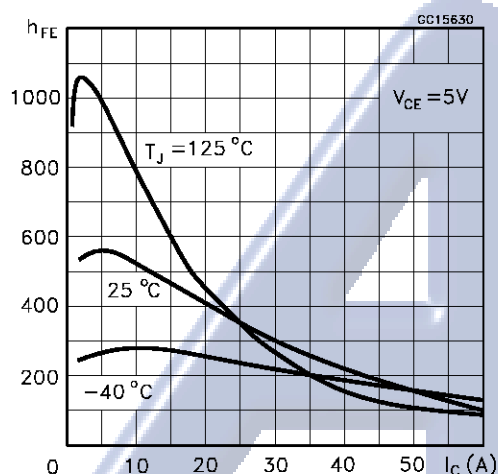
INTERNAL SCHEMATIC DIAGRAM



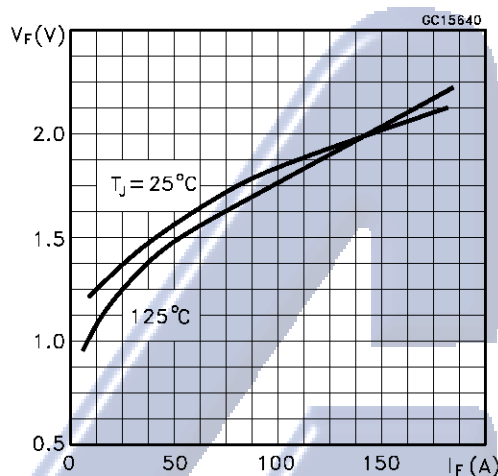
ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CEV}	Collector-Emitter Voltage ($V_{BE} = -5$ V)	600	V
$V_{CEO(sus)}$	Collector-Emitter Voltage ($I_B = 0$)	450	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	7	V
I_C	Collector Current	42	A
I_{CM}	Collector Peak Current ($t_p = 10$ ms)	63	A
I_B	Base Current	4	A
I_{BM}	Base Peak Current ($t_p = 10$ ms)	8	A
P_{tot}	Total Dissipation at $T_c = 25$ °C	150	W
T_{stg}	Storage Temperature	-55 to 150	°C
T_j	Max. Operating Junction Temperature	150	°C
V_{ISO}	Insulation Withstand Voltage (AC-RMS)	2500	°C

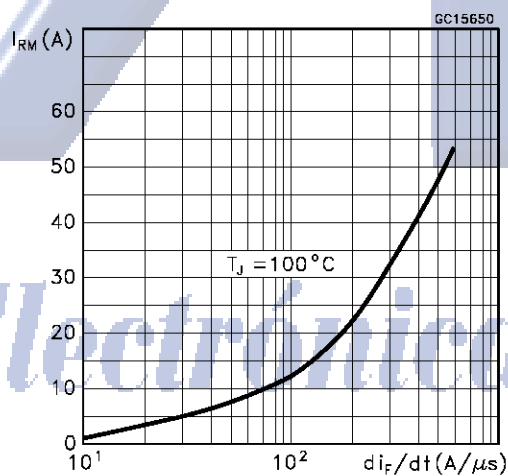
Dc Current Gain



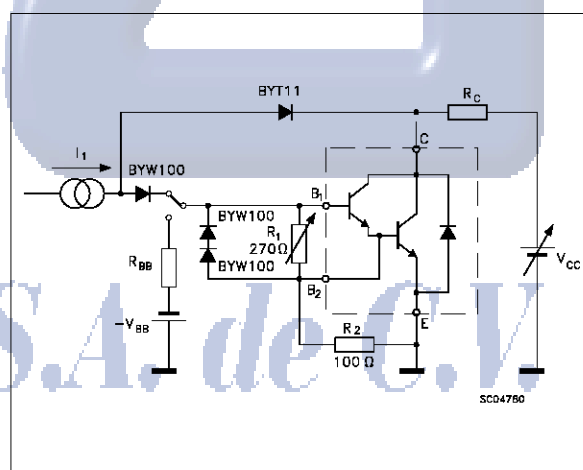
Typical V_F Versus I_F



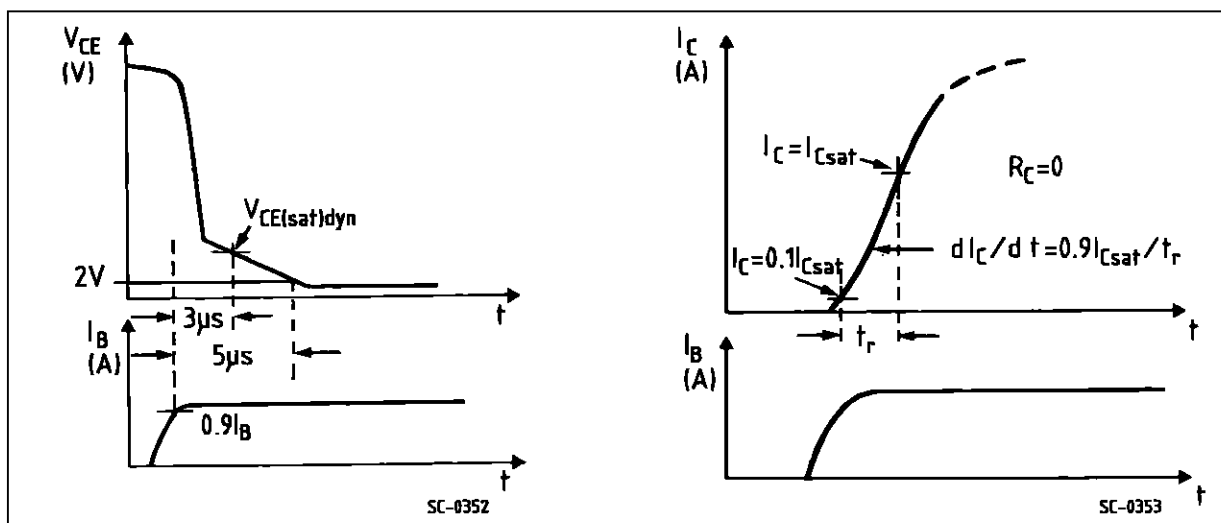
Peak Reverse Current Versus di_F/dt



Turn-on Switching Test Circuit



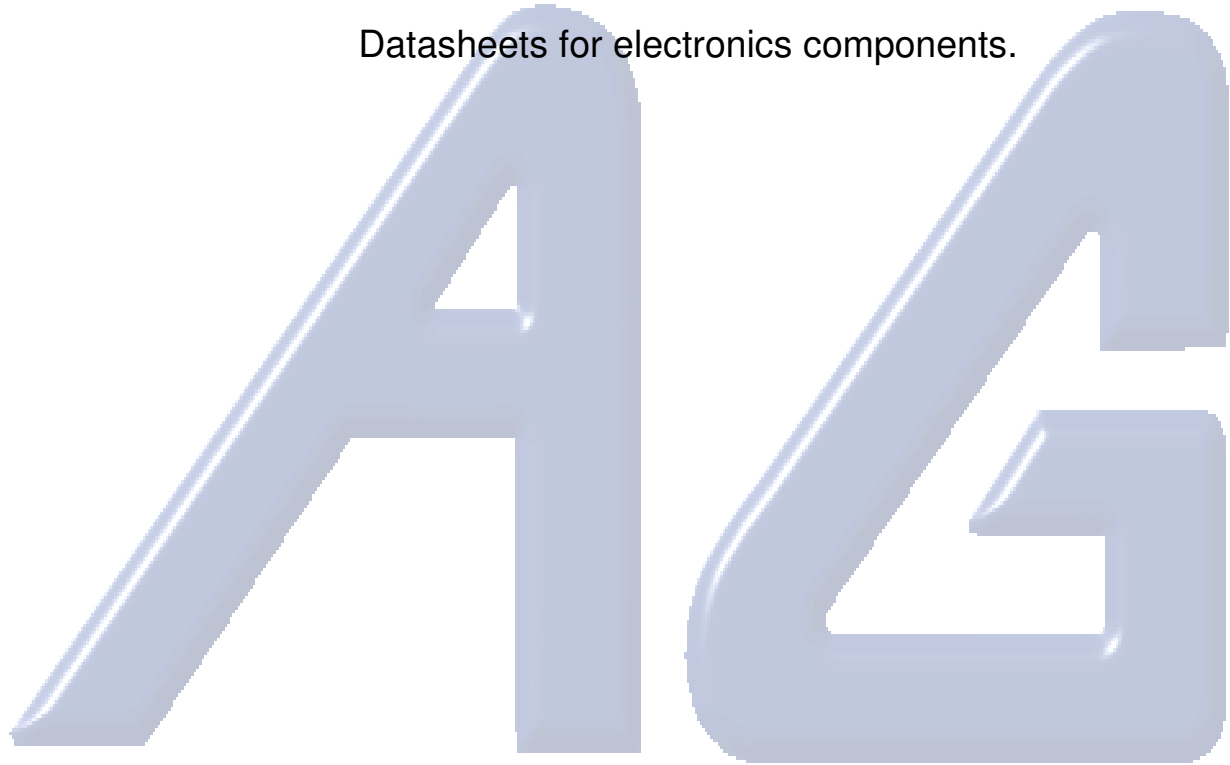
Turn-on Switching Waveforms



This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.



Electrónica S.A. de C.V.